



Structural and optical investigations of TiO₂ films deposited on transparent substrates by sol–gel technique

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ABSTRACT

An inexpensive and effective simple method for the preparation of nano-crystalline titanium oxide (anatase) thin films at room temperature on different transparent substrates is presented. This method is based on the use of peroxy-titanium complex, i.e. titanium isopropoxide as a single initiating organic precursor. Post-annealing treatment is necessary to convert the deposited amorphous film into titanium oxide (TiO₂) crystalline (anatase) phase. These films have been characterized for X-ray diffraction (XRD) studies, atomic force microscopic (AFM) studies and optical measurements. The optical constants such as refractive index and extinction coefficient have been estimated by using envelope technique. Also, the energy gap values have been estimated using Tauc's formula for on glass and quartz substrates are found to be 3.35 eV and 3.39 eV, respectively.

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1. Introduction

Titanium oxide (TiO₂) is one of the most extensively studied transition metal oxide. TiO₂ possesses excellent properties such as chemical resistance, good mechanical strength, transparency, as well as insulating properties. TiO₂ films are widely used in many optical, biomedical, and microelectronic applications because of low cost material with a high refractive index and high dielectric constant [1]. These TiO₂ films carried out for the different applications as in opto-electronic devices, sensors, dye-sensitized photo-voltaic cells, electrochromic displays, planar wave guides, photo-catalysts, etc. [2,3]. The preparation of TiO₂ thin films has received great attention during the past several decades because of its remarkable optical, photo-catalytic and electronic properties. TiO₂ films can be synthesized by various thin film deposition techniques, such as thermal evaporation [4,5], chemical vapor deposition (CVD) [6], metal organic chemical vapor deposition [7],

pulsed laser deposition [8] and sol–gel process [9]. Thin films of TiO₂ are frequently used for coatings due to their high refractive index, and high stability, and its properties are easily affected by the technological conditions of deposition process such as substrate temperature and oxygen partial pressure as well as by the post-deposition heat treatment [10]. Tain et al. [11] have demonstrated that the quantum confinement effect in TiO₂ thin films prepared by electron beam evaporation. They observed that with increasing the grain size, the band gap shifts to from 3.4 eV to 3.2 eV. Optical properties of TiO₂ thin films synthesized by sol–gel process [12], hydrazine processes [13] have been reported by several investigators.

In the present study, we have mainly focused our attention on substrate-type-dependent physical properties of TiO₂ films; apart from these investigations, oxide films are synthesized by sol–gel method because of several advantages, such as low processing temperature, homogeneity, possibility of coating on large area substrates, and the most important cost effective. Unlike physical vapor deposition (PVD) or chemical vapor deposition coating technologies, sol–gel technology does not require any high vacuum equipment. Sol–gel oxide films have many applications as func-

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tional materials in optical, microelectronics, and opto-electronics and for the purpose of corrosion, scratch, abrasion resistance [14]. In the present study, TiO₂ thin films were prepared by spin coating of untreated sol on to uncoated glass and quartz substrates. In this paper we presented the influence of annealing temperature on the structural, morphological and optical properties of TiO₂ thin films.

2. Experimental details

The deposition of TiO₂ films was accomplished by sol–gel technique at ambient room temperature. These films have been prepared by dissolving the titanium alkoxide precursor, i.e. titanium isopropoxide [Ti(OC₃H₇)₄] in an alcoholic bath. To avoid the early precipitation of the oxides 5 ml of concentrated HCl is used per 100 ml of ethyl alcohol. After addition of the concentrated HCl, solution was stirred vigorously up to 1 h with magnetic stirrer. The obtained clear solution was kept in airtight beaker for 1 h till the gel formation. Then, gel has been spin coated on various glass and quartz substrates, respectively. The films were preheated in air at 60 °C for 4 h. After preheating, the films were annealed in air at different temperatures like 250 °C, 300 °C and 350 °C for 8 h, respectively.

A Shimadzu SPM-6000 X-ray diffractometer with Cu K α radiation was employed to study the crystallographic structure of the deposited TiO₂ thin films at ambient room temperature. The XRD pattern of the films deposited on transparent substrates has been recorded in scan ranges of 2θ between 10° and 70°. AFM images were recorded using the Nanoscope IIIa scanning probe microscope in a contact mode. The optical transmittance was measured by single beam spectrophotometer (Ocean Optics, USA) after annealing at different temperatures. The optical constants like refractive index and extinction coefficients were estimated by envelope technique [15].

3. Results and discussion

The visual observation of as-prepared and annealed films was uniform, compact and pinhole free. The TiO₂ films were strongly adherent to the substrate and free from pinholes and visible cracks.

3.1. Structural studies

X-ray diffraction (XRD) technique has been employed to identify the structure of the films. The XRD patterns recorded for the TiO₂ films deposited on glass substrate as deposited and annealed at 350 °C are shown in Fig. 1. It is clear from Fig. 1 that before annealing, no diffraction peaks of TiO₂ have observed indicating that the film is amorphous. Broad hump in the XRD pattern is characteristic of amorphicity and it is seen in all the samples, in the low 2θ region

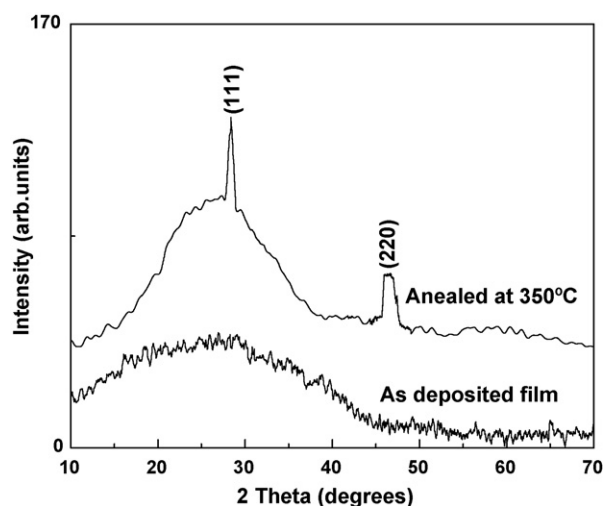


Fig. 1. X-ray diffraction patterns for TiO₂ films for glass substrate annealed at 350 °C.

extending from 15° to 40°, irrespective of the annealing temperature/duration. This broad hump defines an amorphous phase in these films and is assigned to the underlying glass substrate. Also big hump recorded from $2\theta = 20^\circ$ to 40° indicates the presence of glass substrate [16]. However annealing at 350 °C, two sharp diffraction peaks at $2\theta = 28.37^\circ$ and 47.35° are observed corresponding to inter-planer spacing of 3.14 Å and 1.89 Å indicates (1 1 1) and (2 2 0) planes. These peaks clearly indicate the presence of anatase (crystalline) phase of TiO₂. The threshold for the appearance of crystallinity in the films seems to be in the temperature range of 250–300 °C. The films treated at 350 °C and above are thus characterized by the existence of a crystalline phase [17]. The crystalline phase is identified as the anatase phase ($a = 0.37$ nm, $c = 0.95$ nm) with the single observed diffraction peak oriented along the (1 1 1) crystallographic plane, which corresponds well with the JCPDS data file number 21-272. Annealing TiO₂ films in the range from 250 °C to 500 °C, the intensity of the diffraction peaks has been increased, which inferred that TiO₂ film becoming more crystalline. The crystallite size is increased as a function of annealing temperature. The

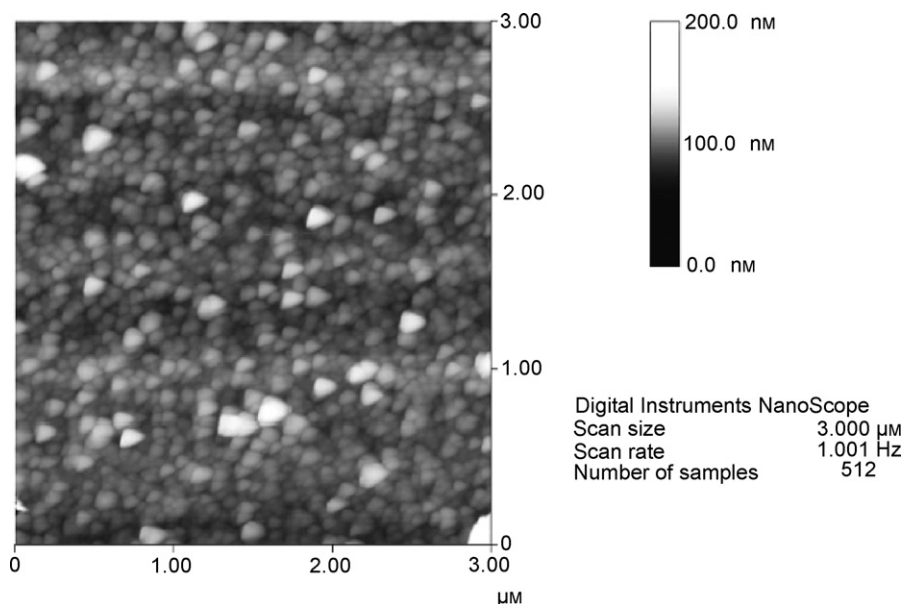


Fig. 2. The morphological AFM image recorded of TiO₂ film on glass substrates annealed at 350 °C.

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